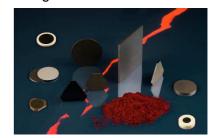


Temex Ceramics offers a wide range of ferrite materials, yttrium garnets ("Y" series or "D" series), magnesium ("U" series), nickel ("N" series) and lithium ("A" series) ferrites, as a result of their own developments on inheritage of the formerly companies CSF, LTT, Thomson. The offer covers need at frequencies from 0.1 to more than 30 GHz, high power, with temperature exigencies as well.

Temex Ceramics manufactures their own ferrite powders from simple oxides or carbonates raw materials, then produce pressed and fired ceramics, machine them at tight tolerances and surface finishing up to polishing. Temex ceramics also supply assemblies of ferrite surrounded with dielectric, silver thick film metallized pieces, complex shapes.



# Symbols / Units

#### **Magnetism parameters**

Great letters: time constant (DC) / Small letters: frequency, time dependant (RF)

Symbol	Parameter	MKSA system	CGS system
$\begin{array}{c} B \\ Br \\ M \ (4\pi M_s \ or \ M_s), \\ m \end{array}$	Magnetic induction Remnant induction Volume magnetization (saturation)	Tesla (T)	Gauss (=10 <sup>-4</sup> Tesla)
$\begin{array}{c} H,\ H_r\\ H_a\\ H_c\\ h,\ h_c\\ \Delta H\\ \Delta H_{eff}\\ \Delta H_K \end{array}$	Magnetic field (magnetizing force), resonance Anisotropy field Coercive force Magnetic wave field, critical wave field Ferromagnetic resonance line width Effective resonance line width Spin wave line width	A/m	Oersted (Oe) (=10 <sup>3</sup> /4π A/m)
$\mu_0$	Vacuum permeability	$4\pi 10^{-7}$ H/m B = $\mu_0$ (H+M)	1 B = H+4πM
$\mu = \mu_0 \mu_r$	Permeability	$B = \mu_0.\mu_r.H$	$B = \mu_r.H$
χ	Magnetic susceptibility = M/H, m/h	-	-
$\mu_{r}$	Relative permeability	$\mu_r = 1 + \chi$	μr = 1 +4πχ (or 1+χ)
α	Magnetization temperature coefficient: $\frac{\Delta M_2}{M_S \Delta T}$	10 <sup>-3</sup> .K <sup>-1</sup>	10 <sup>-3</sup> .℃ <sup>-1</sup>
f	Wave frequency	MHz	MHz
γ	Gyromagnetic ratio: $f = \gamma H_r$	~35 10 <sup>-3</sup> MHz. m / A	~2.8 MHz / Oe
<b>G</b> eff	Lande factor ~ 2	$= \gamma / 0.0176$	$=\gamma/1.4$

In the below text, CGS system is mainly used with simplified expression (without the factor  $4\pi$ ).



#### **Dielectric**

Symbol	Parameter
ε'	Relative permittivity (real part)
ε"	Relative permittivity (imaginary part)
$\epsilon_{r}$	Relative complex permittivity
tanδ	Dielectric loss tangent: $tan\delta = \epsilon''/\epsilon'$

#### **Miscellaneous**

Symbol	Parameter	Unit
T,Tc	Temperature, Curie temperature	K
Ra	Surface roughness	μm

# **I. Basic Properties**

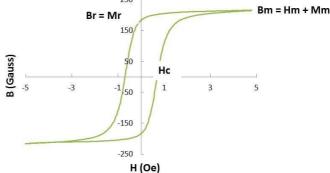
Ferrite materials are used in microwave applications to perform various non-reciprocal devices such as isolators, circulators, diplexers, filters, phase shifters etc. They have dielectric and magnetic properties due to the presence of magnetic ions such as iron within the composition.

## I.1 Magnetic properties

## **Magnetization Ms**

This property is based on the alignment of the spins of electrons parallel to an applied magnetic field H. Because the material is a "soft magnetic material", a small field (close to coercive force  $H_c$ ) of about 1 to few Oe is enough to get its magnetization value (Mm = $B_m$  - Hm) close to its saturated maximum  $M_s$  (values in the range 290 to 5000 Gauss). This is shown on the curves of the hysteresis loop. However this Ms value is really obtained at much higher field, the measurement is made with a 8000 Oe magnet.

The hysteresis loop also shows, how for the null H field, the material can be in a remnant state with an induced field Br different from zero. This is used in phase shifters to monitor phase shift through the ferromagnetic resonance at Mr.



By increasing temperature of the ferrite, the aligning of the spins parallel to the H field is more and more difficult due to thermal agitation. The magnetization becomes null at the Curie temperature Tc, which are in the range of 120 to 650℃. The evolution of the magnetization with temperature is measured by the parameter:

$$\alpha = \frac{\Delta M_s}{M_s \Delta T}$$
 in the common range of T: -20 to +60°C



### **Gyromagnetic resonance – Lande factor geff**

The gyromagnetic resonance, and so the non-reciprocal effect, is created in ferrite devices isolators, circulators, phase shifters, switches under a static magnetic field  $\vec{H}$ .

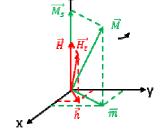
In case of saturation of the ferrite to  $M_s$ , and in case of a wave propagating parallel to the z axis, the microwave field  $\vec{h}$  is in a plane "x y" perpendicular to the z axis and rotating at a frequency f magnetization  $\vec{M}$  discloses a precession motion about the field  $\vec{H}$  at the

frequency f. There is a resonance for  $\|\vec{H}\| = H_r$  given by:

$$H_r = \frac{f}{\gamma}$$

-  $\gamma$  is the gyromagnetic ratio and is related to the effective Lande factor  $g_{\text{eff}}$  as

-  $\gamma$  = 1.4 . g<sub>eff</sub>.MHz/Oe. g<sub>eff</sub> is about 2 depending on the material:  $2 \le g_{eff} \le 2.3$ 



### Permeability, gyro-resonance line width ∆H, non-reciprocal effect

The magnetization  $\overline{m}$  is related to the microwave magnetic field  $\overline{h}$  with the tensor of susceptibility  $\overline{\chi}$ :  $\overline{m} = \overline{\chi} \times \overline{h}$ . This tensor (named Polder tensor) owns two eigenvalues associated respectively to a positive (+) circularly polarized wave and to a negative (-) circularly polarized wave. Thus in a system of coordinates rotating about H axis at the frequency f, the magnetization  $\overline{m}$  is described with two components only,  $m_+$  and  $m_-$ :  $m_+ = \chi_+ h_+$   $m_- = \chi_- h_-$ 

The susceptibilities  $\chi_+$  and  $\chi_-$  are complex numbers. The real and the imaginary part of each of these values are noted  $\chi_+$ ,  $\chi_-$ ,  $\chi_-$ ,  $\chi_-$ ,  $\chi_-$ ,  $\chi_-$ . The imaginary parts represent the loss. Complex permeability  $\mu$  is related to susceptibility:

$$\mu_{\pm} = 1 + \chi_{\pm}, \ \mu_{\pm} = \mu_{\pm}' - j \mu_{\pm}'', \ \mu_{\pm}' = 1 + \chi_{\pm}', \ \mu_{\pm}'' = \chi_{\pm}''$$

Permeability can be expressed as a function of frequency or magnetic field H, or normalized to H<sub>r</sub>, thus fig.1

$$\mu_{\pm}' = 1 + \frac{M_s}{H_r} \frac{\left(\frac{H}{H_r} \mp 1\right)}{\left(\frac{H}{H_r} \mp 1\right)^2 + \left(\frac{\Delta H}{2H_r}\right)^2} \quad \mu_{\pm}'' = \frac{M_s}{H_r} \frac{\frac{\Delta H}{2H_r}}{\left(\frac{H}{H_r} \mp 1\right)^2 + \left(\frac{\Delta H}{2H_r}\right)^2}$$

H is the internal static magnetic field  $H_r$  is the resonance field  $M_s$  is the saturated magnetization  $\Delta H/Hr$  is the midpoint width of the Lorentz curve  $\Delta H$  gyromagnetic line width  $\gamma$  is the gyromagnetic ratio

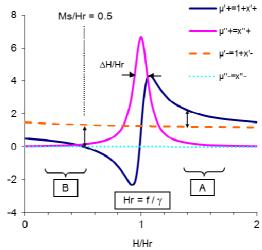


Figure 1  $\mu$ '+ ,  $\mu$ '- ,  $\mu$ "+ ,  $\mu$ "- , as a function of H/H<sub>r</sub> "B": below H<sub>r</sub> resonance field (low field H) "A": above H<sub>r</sub> resonance field (high field H)

Within a given magnetic field range, it is possible to find values of H such that the permeabilities  $\mu_+$  and  $\mu_-$  are different, while  $\mu_+$  and  $\mu_-$  have very low values (fig 1). This property has for consequence, the <u>non-reciprocity</u> of devices behavior: the greater the difference  $\underline{\Delta}\underline{\mu}$  between  $\mu$ '+ and  $\mu$ '-, the more efficient the device. The field H can be either lower or higher than the resonant field H<sub>r</sub>



#### Operation **b**elow resonance (zone B in fig 1)

The difference  $\Delta\mu$  is greater than in the case of high field (B zone in fig 1) and more constant over the H field locally. Moreover the external field required is lower, and so the magnet strength too so that smaller magnets are required.

Nevertheless magnetization of the ferrite should be lower than a certain limit and is a limiting factor for the difference  $\Delta\mu$  since magnetization is a multiplicative factors in all terms of the susceptibility. The limit is due to the phenomenon of natural resonance in unsaturated materials. This leads to "low magnetic field loss" (fig 2). Consequently, for a given frequency f, the material selected must have magnetization lower than the field of resonance Hr, so lower than  $f/\gamma$ , unless it is to be used above the resonance.

Finally at low field H, the magnetisation should be chosen according to:

$$\frac{1}{3} < \frac{\gamma M_s}{f} < \frac{3}{4}$$

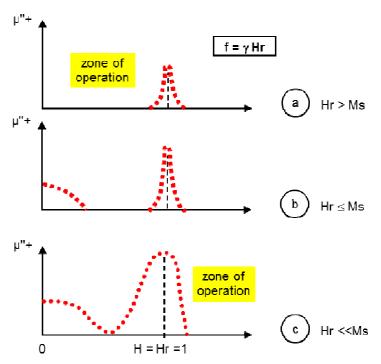


Figure 2 : permeability  $\mu_{+}^{"}$  versus static field H

#### Operation above resonance (zone A in fig 1)

In that case the magnetization may be greater than the limit of  $f/\gamma$  and so efficiency is improved as a consequence of a larger difference in  $\Delta\mu$ . This case should be applied as soon as magnet conditions for H field are fulfilled (strength, temperature behaviour linked to the ferrite's one, etc.). Another advantage is seen in the case of power losses as indicated forward.

#### Effective line width $\Delta H_{eff}$

The magnetic losses in the ferrites affect the insertion loss of the device. It is related to the imaginary part of the permeability of the positive polarization  $\mu''_+$ , which increases with the gyromagnetic line width  $\Delta H$  (fig.1).

Experiment shows that the curve  $\mu''_{+}(H)$  far away from the resonance is a Lorentz curve with an effective line width denoted  $\Delta H_{eff}$  smaller than  $\Delta H$ . Near the resonant frequency, the line width is broadening by several phenomena such as porosity, magneto crystalline anisotropy.

There is much practical interest involved in the concept of effective line width  $\Delta H_{\text{eff}}$  than line width  $\Delta H_{\text{,}}$  far from resonance.

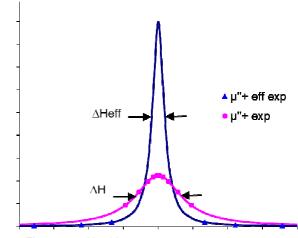


Figure 3 : ∆H, ∆H<sub>eff</sub>



The imaginary parts of permeability  $\mu_{+}$  represent losses in the material:

- At the vicinity of the resonance,  $\mu_{+}$  describes a Lorentz curve the half width of which, denoted  $\Delta H$
- From the values of  $\mu^{''}_{+}$ , far from resonance, a Lorentz curve can be extrapolated the half width of which, denoted  $\Delta H_{eff}$ , corresponds to the off resonance magnetic losses.

Depending on their compositions, the ferrites have line width  $\Delta H$  in the range 10 to 500 and  $\Delta H_{eff}$  in the range 4 to 50.

#### Spin wave line width $\Delta H_k$

Above a certain microwave power level, nonlinear phenomena take place resulting in additional magnetic loss which rapidly becomes prohibitive in the devices.

The critical magnetic microwave field  $h_c$ , from which such effects appear, depends on the applied static field. The nonlinear effects are associated with the excitation of the spin waves, the attenuation of which is described by  $\Delta H_k$ .

For a certain static magnetic field H denoted Hsub, there is a minimum of the microwave magnetic field hc related to  $\Delta H_{\textbf{k}}$ 

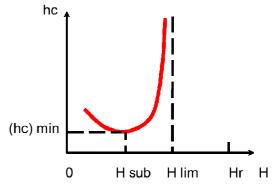


Figure 4: non-linear effect critical field hc versus static field

$$h_c \min = \frac{2f\Delta H_k}{\gamma M_s}$$

The higher the value of  $\Delta H_k$ , the better the high power behavior.

For a static magnetic field higher than H lim, there is no effect of the power on losses: this is the case for devices operating at high static field (above resonance).

The ferrites have  $\Delta H_k$  from 1 to more than 20. The relation between the line widths is  $\Delta H_k < \Delta H_{eff} < \Delta H$ 

## **I.2 Dielectric properties**

The dielectric properties of the ferrites are also of importance in the applications. The relative real permittivity  $\varepsilon$ ' is within the range of about 12 to 16 and affects the wave length in the material and the impedance. The relative imaginary part of the permittivity  $\varepsilon$ ' or the dielectric loss tangent  $tg\delta = \frac{\varepsilon''}{\varepsilon'}$  affects the insertion losses. Ferrites, depending on their compositions have dielectric loss tangent at 10 GHz between 10<sup>-4</sup> and 10<sup>-3</sup>. In this range, the insertion loss of the device is more affected by the magnetic losses.



#### **I.3 Characterization**

Four parameters are tested in standard production. The result of test is compared with the values in the tables at the end: Ms,  $\Delta$ H,  $\epsilon$ ',  $\tan\delta$ 

The Landé factor g<sub>eff</sub> and the hysteresis cycle parameters are given on request.

Others parameters such as Tc,  $\Delta H_{eff}$ ,  $\Delta H_{k}$  and  $\alpha$  are not tested but the values are given in the tables, considered as heritage.

#### Saturation Magnetization M<sub>s</sub>

Saturation magnetization is measured at room temperature by the Weiss method. A sample of one gram typically is moved through the air gap of a magnet delivering a magnetic field of 8000 Oe. A flux variation is produced through Helmholtz bobbins fixed on the magnet poles and read on an integrator: the signal of a material is compared to a pure nickel's one with admitted value is 54.56 Gauss.cm<sup>3</sup>/g

#### **Gyromagnetic line width ∆H and effective Lande Factor**

The effective Landé factor  $g_{\text{eff}}$  and line width  $\Delta H$  are measured in a rectangular cavity at 9.3 GHz and at room temperature. The test sample is a sphere of about 1mm in diameter. The test complies with the IEC 60556 publication.

### Relative dielectric constant $\epsilon'$ and dielectric loss tangent tan $\delta$

The permittivity is measured using a rod of about 1mm in diameter in a rectangular cavity at 8.2 GHz.

## **Hysteresis parameters**

Temex Ceramics offers the possibility to perform hysteresis on request and give remnant induction Br, coercive field Hc, temperature dependence. Values are given for the Axx families and NZ50 material.

A toroidal sample is double winded and used as a transformer. The primary winding magnetizes the sample through a 50 Hz frequency signal. The applied field H is proportional to the primary current; the signal induced in the secondary winding is proportional to the magnetic flux variation and is integrated to obtain the magnetic induction B.

The induction value Bm is obtained for an applied field of 5 Hc.



# **II. User Guide**

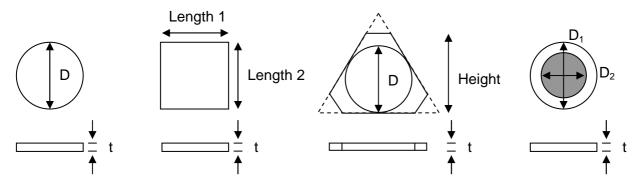
#### **Material properties synthesis**

Table below summarizes the properties of materials in term of magnetization, stability of magnetization, line widths.

Ferrite family	Chemical composition	composition (below resonance)		Power behaviour ΔH <sub>k</sub> (Oe)	Temperature stability α (10 <sup>-3</sup> /°C)
Y1xx	Y-Gd	1.55 ~ 10.9	3 ~ 45	1.5 ~ 13	0.9~2.2
Y2xx	Ca-V-Y (CVG)	Ca-V-Y (CVG) 1.55 ~ 10.9 2		1	2.6~3.7
Y3xx	Y-Al	0.34~6.2	4	2	2.6~5
Y4xxx	CVG-Gd	1.55~6.2	12~18	9~12	0.8~1.4
Y7xx	Y-Gd-Al	0.34~6.2	6~15	5~10	0.5~3.4
Y9xx	Y-Gd-Al Co-doped	0.34~10.9	9~15	25~46	0.3~1.3
Dx	Y-Gd-Al Dy-doped	0.34~10.9	29~63	10~20	0.5~3
Uxx	Mn-Mg	1.55~36	6	4	2.2~3.3
Axxx	Li	6.2~40	4~9	3~10	0.9~1.6
Nxxx	Ni	1.55~40	30~50	12~25	0.7~2

#### **Shapes**

Typical range of shapes which can be produced including single ferrite (F), assembly (FDA) with typical dielectric constant 16, others on request



## **Dimensioning (mm)**

A wide range of dimensions can be made based on customer specifications

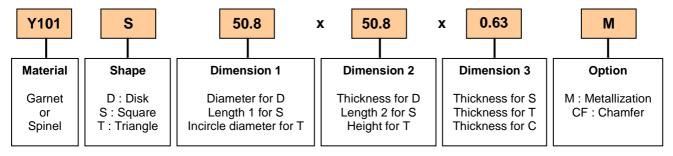
- Disks: diameter 1.5 up to 55 mm (typical value)
- Square: max length 50.8 x 50.8 mm / Thickness 0.5 mm up to 3 mm (typical value)
- Triangle: in-circle diameter up to 50 mm (typical value)

## Tolerances on dimensions (mm)

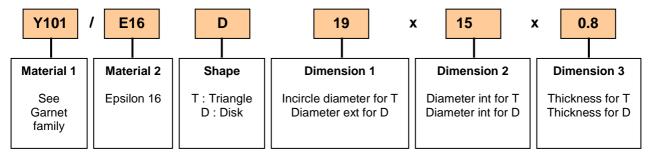
- Standard tolerances are +/-0.05 mm on both diameter and thickness.
- As-fired parts (no machining requested => lower cost) are available for +/-1% tolerance.
- Smaller tolerances can be considered on request.



#### How to order



Example for ferrite: Y101 S50.8x50.8x0.63 M



Example for FDA: Y101/E16 D19x15x0.8

### **Surface finishing**

As-fired parts can be grinded, lapped or polished. Standard average peak-to-valley height (Ra) is specified here below.

Surface finishing	Ra (micrometer)	Ra (micro-inch)	Remarks
Standard	0.8	24	All ferrites
Lapped	0.4	16	All ferrites
Polished	0.1	4	All ferrites except A or U family

#### Metallization

Thick film: Silver Thin film: on request

#### Chamfer

As per customer specification.



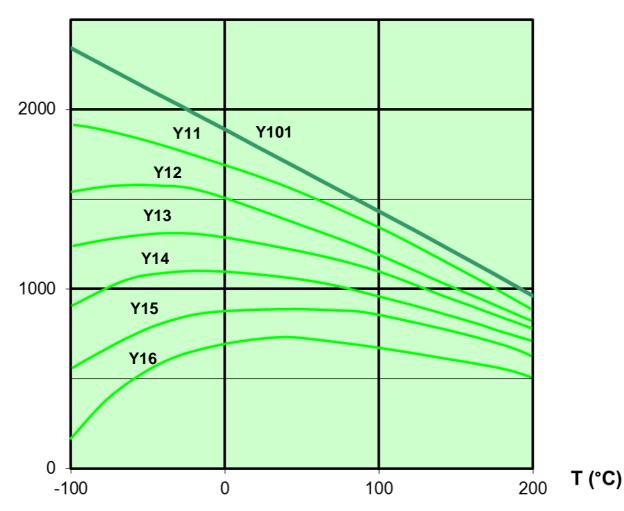
### <u>Y - Gd</u>

#### Yttrium - Gadolinum

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{eff}$	ΔH (Oe) +20%	$\Delta H_{ ext{eff}}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y101*	1820	280	2.02	18	3	1.5	15	2	2.2
Y11 Y12 Y13 Y14 Y15	1600 1420 1250 1100 900	280 280 280 280 280	2.00 2.01 2.01 2.02 2.03	50 60 75 95 130	8 14 21 28 36	3 5 7 9 11	15.3 15.3 15.3 15.4 15.4	2 2 2 2 2	1.8 1.5 1 0.5 0.7
Y16	750	280	2.02	170	45	13	15.4	2	0.9

<sup>\*</sup> Pure Yttrium iron garnet

## Ms (Gauss)



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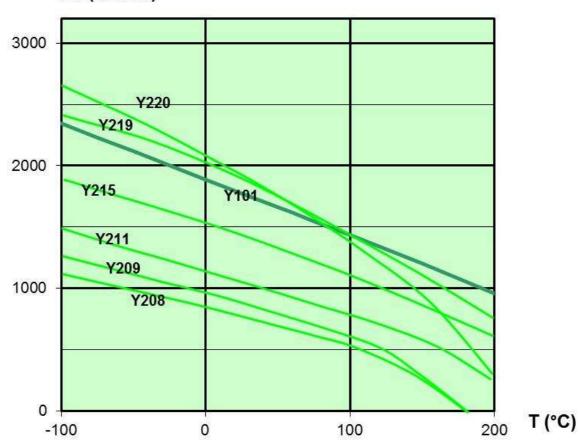


## Y - Ca - V - In or Zr

#### Yttrium - Calcium - Vanadium - Indium or Zirconium

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{eff}$	ΔΗ (Oe) +20%	$\Delta H_{ ext{eff}}$ (Oe)	$\Delta H_k$ (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y220	1950	205	2.01	10	2	1	15.4	2	3.1
Y219	1900	240	2.02	15	3	1.5	15.2	2	2.6
Y218	1850	215	2.01	10	2	1	14.8	2	2.8
Y216	1600	218	2.01	10	2	1	14.8	2	2.6
Y215	1450	215	2.01	10	2	1	14.7	2	2.7
Y212	1200	209	2.01	10	2	1	14.5	2	2.9
Y211	1100	205	2.01	10	2	1	14.2	2	3
Y210	1000	200	2.01	10	2	1	14.2	2	3.3
Y209	900	180	2.01	10	2	1	14.1	2	3.5
Y208	800	177	2.01	10	2	1	14	2	3.7

## Ms (Gauss)



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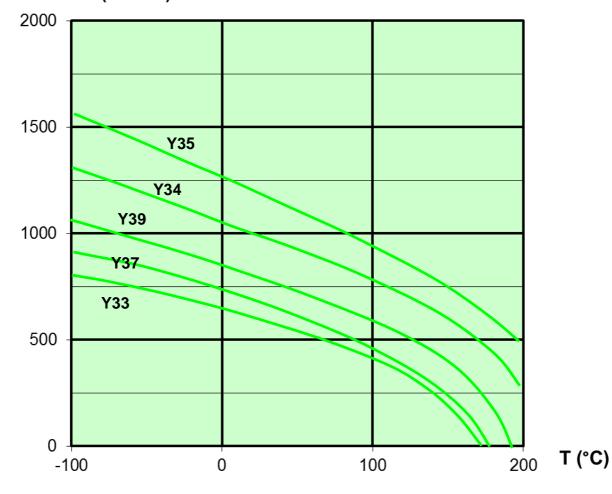




### <u>Y - Al</u>

#### Yttrium - Aluminum

Type	Ms (Gauss) ±5%	Tc (℃)	$g_{eff}$	ΔH* (Oe) +20%	$\Delta H_{ ext{eff}}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y35	1200	225	2.01	40	4	2	14.9	2	2.6
Y34	1030	210	2.01	40	4	2	14.9	2	2.7
Y39	800	195	2.01	40	4	2	14.6	2	2.9
Y38	760	190	2.01	40	4	2	14.5	2	2.9
Y37	680	180	2.01	40	4	2	14.5	2	2.9
Y33	615	175	2.01	40	4	2	14.5	2	3.2
Y30	565	160	2.01	30	4	2	14.4	2	3.4
Y32	420	135	2.01	30	4	2	14.4	2	3.8
Y31	370	125	2.01	30	4	2	14.1	2	4.1
Y36	290	115	2.01	25	4	2	14	2	4.6

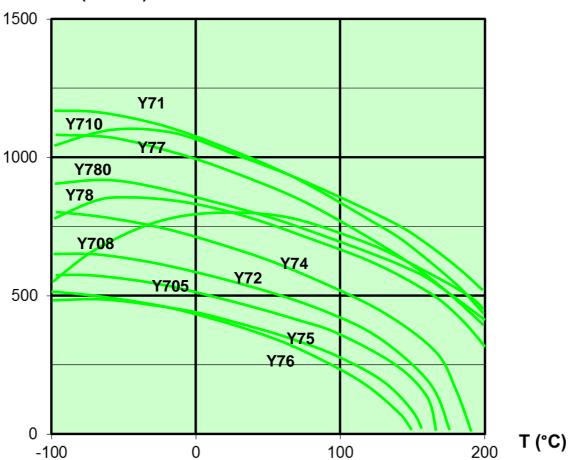




#### **Y - AI - Gd**

#### Yttrium - Aluminum - Gadolinum

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{eff}$ (Oe)	$\Delta H_k$ (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y71	1020	235	2.01	60	7	5	15	2	2.2
Y710	1020	240	2.02	75	9	7	15	2	1.7
Y77	950	230	2.01	60	6	5	14.9	2	2
Y780	830	235	2.02	60	6	5	14.8	2	1.6
Y78	800	220	2	80	8	7	15	2	1.3
Y708	800	260	2.04	140	15	10	15.2	2	0.5
Y74	570	190	2.01	60	6	5	14.9	2	2.3
Y72	540	175	2.01	60	6	5	14.6	2	2.3
Y705	470	170	2.02	65	6	5	14.3	2	2.8
Y75	400	160	2.03	65	6	5	14.3	2	2.7
Y76	390	150	2.02	50	6	5	14.2	2	3.4

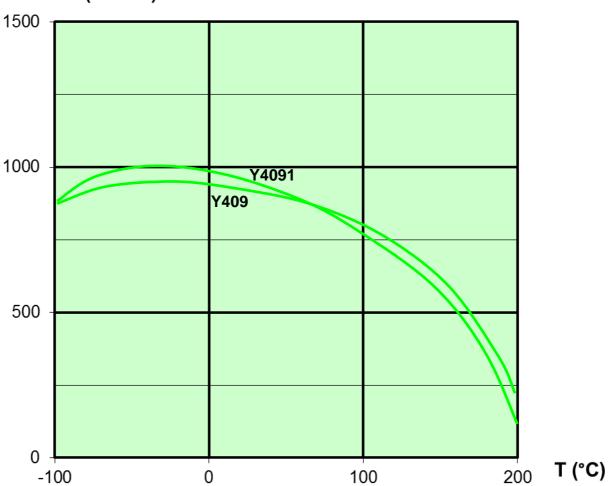




#### <u>Y - Ca - V - Zr - Gd</u>

#### Yttrium - Calcium - Vanadium - Zirconium - Gadolinum

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{ m eff}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y4091	960	195	2.02	35	12	9	15.2	2	1.4
Y409	920	223	2.02	50	18	12	15.2	2	0.8

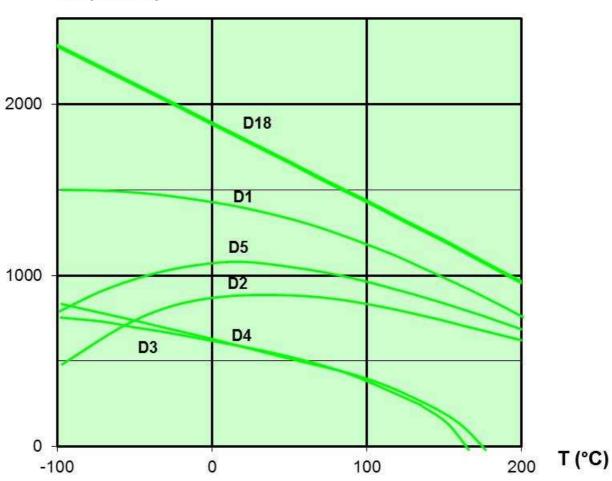




#### **Y- Gd - Dy - Al**

## Yttrium-Dysprosium or Gadolinum-Dysprosium or Aluminum-Dysprosium

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{ m eff}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
D18	1760	280	2.02	85	54	18	15	2	2.2
D1	1400	270	2	110	41	14	15.5	2	1.4
D5	1070	270	2.02	150	55	18	15.5	2	0.5
D2	900	270	2.01	185	63	20	15.5	2	0.8
D3	590	175	2	85	29	10	14.5	2	3.5
D4	580	170	2	140	56	19	14.4	2	3

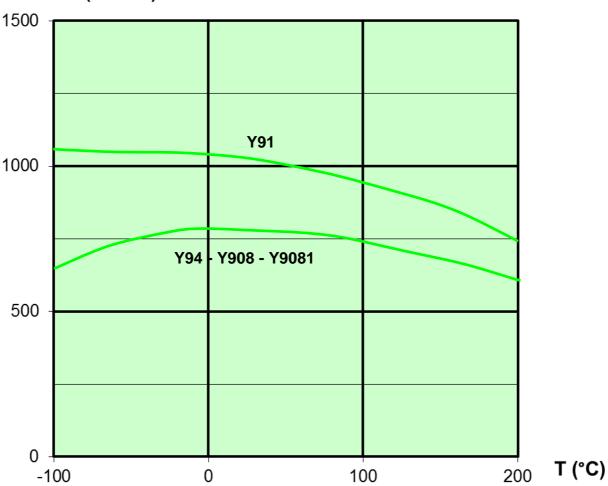




### **Y - Gd - Al - Co**

#### Yttrium - Gadolinum - Aluminum - Cobalt

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{ ext{eff}}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
Y91	1020	240	2.02	60	25	9	15.1	2	1.3
Y94	780	250	2.02	75	40	13	15.2	2	0.3
Y908	780	250	2.02	85	43	14	15.2	2	0.3
Y9081	780	250	2.02	120	46	15	15.2	2	0.3

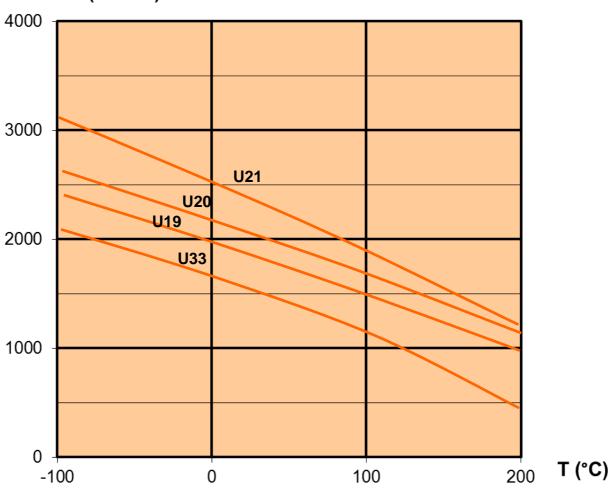




### Mg - Mn - Al

### Magnesium-Manganese or Magnesium-Manganese-Aluminum

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{eff}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2
U21	2400	275	2.03	290	6	4	13	3	2.7
U20	2100	300	2.01	360	6	4	13	3	2.3
U19	1900	280	2.01	350	6	4	13	3	2.2
U33	1600	230	2.02	290	8	4	12.4	3	3.3





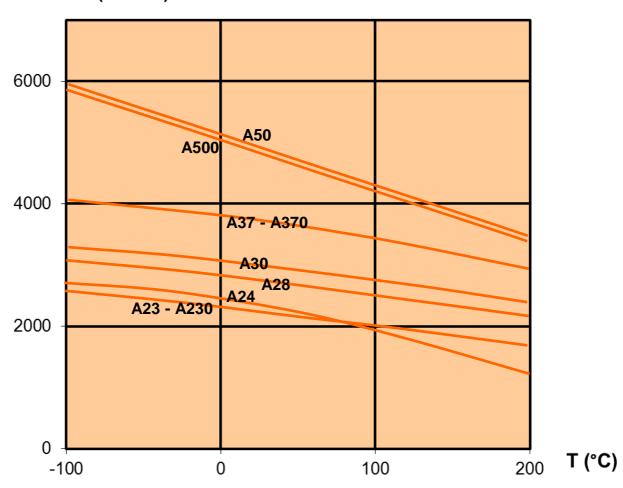
EXXELIA

# **MICROWAVE FERRITES & FDA**

### <u>Li – Zn - Ti - Mn - (Co)</u>

### Lithium - Zinc - Titanium - Manganese - (Cobalt)

Туре	Ms (Gauss) ±5%	Tc (℃)	$g_{ ext{eff}}$	ΔH (Oe) +20%	$\Delta H_{eff}$ (Oe)	$\Delta H_k$ (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2	Br (Gauss)
A50	5000	450	2.06	170	4	3	15.3	5	1.6	3300
A500	4900	450	2.06	200	20	10	15.3	5	1.6	3200
A37	3700	565	2.08	400	4	3	16	5	1	2500
A370	3700	565	2.07	400	7	6	15.9	5	1	2500
A30	3000	555	2.08	450	4	3	16.4	5	8.0	2000
A28	2800	540	2.08	450	4	3	16.6	5	0.9	1900
A24	2450	390	2.08	250	4	3	16.8	5	1.6	1700
A23	2300	505	2.08	450	4	3	16.8	5	1.2	1600
A230	2300	505	2.08	450	9	8	16.7	5	1.2	1600





### Ni - Zn - Al

## Nickel or Nickel-Zinc or Nickel-Aluminum (with Cobalt - Manganese - Copper)

Type	Ms (Gauss) ±5%	Tc (℃)	$g_{eff}$	ΔH (Oe) +20%	$\Delta H_{eff}$ (Oe)	ΔH <sub>k</sub> (Oe)	ε ±5%	tgδ 10 <sup>-4</sup> max	α 10 <sup>-3</sup> /℃ ±0.2	Br (Gauss )
NZ50	5000	375	2.1	125	30	12	13.7	5	2	3650
NZ40	4000	470	2.2	200	40	15	13.4	5	1.7	-
N32	3200	560	2.3	200	50	25	13.2	6	1	-
N28	2800	550	2.3	200	50	25	13	6	0.8	-
N24	2400	520	2.3	200	50	25	12.7	6	0.7	-
N19	1900	480	2.3	200	50	25	12.4	6	0.7	-

